BAT54T1

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Preferred Device

Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 Volts (Typ) @ $I_F = 10 \text{ mAdc}$
- Pb-Free Package is Available

MAXIMUM RATINGS (T_J = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V_{R}	30	V
Forward Power Dissipation, FR–5 Board (Note 1)	P _F	W. 100Y.	20M
@ T _A = 25°C Derate above 25°C	W	400 3.2	mW mW/°C
Thermal Resistance, Junction-to-Case	$R_{\theta JL}$	174	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	492	°C/W
Forward Current (DC)	IF	200 Max	mA
Non–Repetitive Peak Forward Current t _p < 10 msec	I _{FSM}	600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	I _{FRM}	300	mA
Junction Temperature	TJ	-55 to 125	°C
Storage Temperature Range	T _{stg}	-55 to +150	√°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.



ON Semiconductor®

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30 VOLT SCHOTTKY BARRIER DETECTOR AND SWITCHING DIODES





SOD-123 CASE 425 STYLE 1

MARKING DIAGRAM



SB = Device Code M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

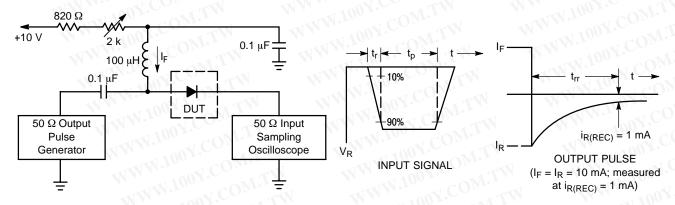
Device	Package	Shipping [†]		
BAT54T1	SOD-123	3000 / Tape & Reel		
BAT54T1G	SOD-123 (Pb-Free)	3000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage ($I_R = 10 \mu A$)	V _{(BR)R}	30	IN-	_	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	Ст	N.CON	7.6	10	pF
Reverse Leakage (V _R = 25 V)	I _R	OOX-CO	0.5	2.0	μAdc
Forward Voltage (I _F = 0.1 mAdc)	V _F	1007.C	0.22	0.24	Vdc
Forward Voltage (I _F = 30 mAdc)	V _F	N.100Y	0.41	0.5	Vdc
Forward Voltage (I _F = 100 mAdc)	V _F	W.100	0.52	0.8	Vdc
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}, Figure 1)$	t _{rr}	MAT TO	ON.COL	5.0	ns
Forward Voltage (I _F = 1.0 mAdc)	V _F	MM.	0.29	0.32	Vdc
Forward Voltage (I _F = 10 mAdc)	V _F	WWW	0.35	0.40	Vdc
Forward Current (DC)	ON TVIF	WW	1001	200	mAdc
Repetitive Peak Forward Current	I _{FRM}	701	M . = 00	300	mAdc
Non-Repetitive Peak Forward Current (t < 1.0 s)	I _{FSM}	-W	N W.10	600	mAdc
			14 77 6	-	<u> </u>



Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA.

2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.

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3. t_p » t_{rr}

Figure 1. Recovery Time Equivalent Test Circuit

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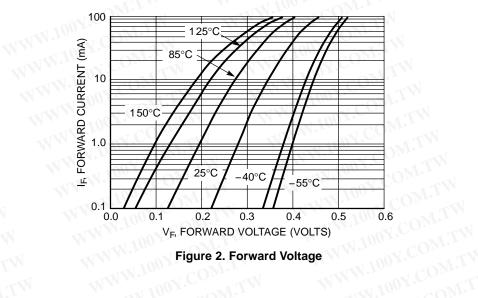


Figure 2. Forward Voltage

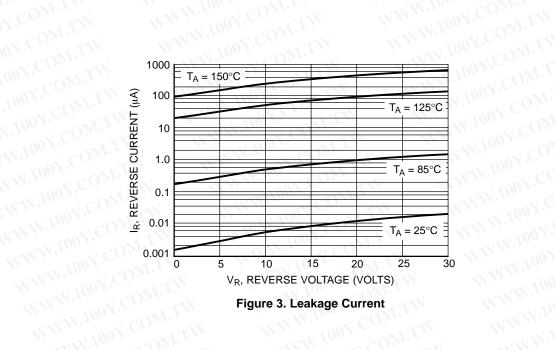
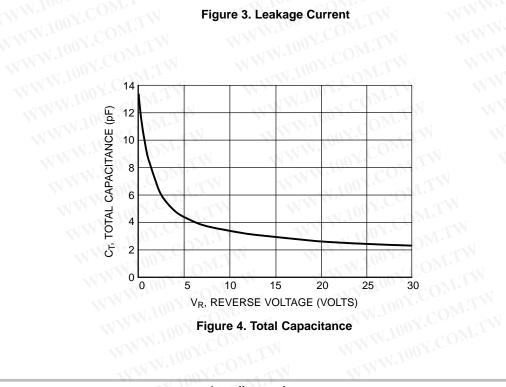


Figure 3. Leakage Current

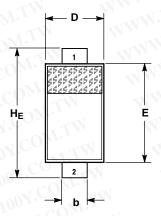


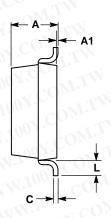
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BAT54T1

PACKAGE DIMENSIONS

SOD-123 PLASTIC PACKAGE CASE 425-04 ISSUE E





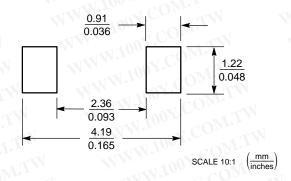
NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

M.	MI	LLIMETE	RS	-11	INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
C	//		0.15		~ ~~	0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
Εd	2.54	2.69	2.84	0.100	0.106	0.112
HE	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25	17770		0.010	, o E	

STYLE 1: PIN 1. CATHODE 2. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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